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### BD440/442

# **Medium Power Linear and Switching Applications**

Complement to BD439, BD441 respectively



## **PNP Epitaxial Silicon Transistor**

Absolute Maximum Ratings  $T_C=25^{\circ}C$  unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: BD440	- 60	V
	: BD442	- 80	V
V <sub>CES</sub>	Collector-Emitter Voltage		
	: BD440	- 60	V
	: BD442	- 80	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: BD440	- 60	V
	: BD442	- 80	V
$V_{EBO}$	Emitter-Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 4	Α
I <sub>CP</sub>	*Collector Current (Pulse)	- 7	Α
I <sub>B</sub>	Base Current	- 1	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	36	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 1 50	°C

### Electrical Characteristics $T_{C}=25$ °C unless otherwise noted

Symbol	Paramete	er	Test Condition	Min.	Тур.	Max.	Units
V <sub>CFO</sub> (sus)	Collector-Emitter Sustainir	ng Voltage					
0201		: BD440	$I_{C} = -100 \text{mA}, I_{B} = 0$	-60			V
		: BD442	7 5	-80			V
CBO	Collector Cut-off Current	: BD440	$V_{CB} = -60V, I_{E} = 0$			- 100	μΑ
		: BD442	$V_{CB} = -80V, I_{E} = 0$			- 100	μΑ
CES	Collector Cut-off Current	: BD440	$V_{CE} = -60V, V_{BE} = 0$			- 100	μΑ
		: BD442	$V_{CE} = -80V, V_{BE} = 0$			- 100	μΑ
EBO	Emitter Cut-off Current		$V_{EB} = -5V, I_{C} = 0$			- 1	mA
1 <sub>FE</sub>	* DC Current Gain	: BD440	$V_{CE} = -5V, I_{C} = -10mA$	20	140		
		: BD442		15	140		
		: BD440	$V_{CE} = -1V, I_{C} = -500mA$	40	140		
		: BD442		40	140		
		: BD440	$V_{CE} = -1V, I_{C} = -2A$	25			
		: BD442	1	15			
√ <sub>CE</sub> (sat)	* Collector-Emitter Saturati	on Voltage	I <sub>C</sub> = - 2A, I <sub>B</sub> = - 0.2A			- 0.8	V
V <sub>BE</sub> (on)	* Base-Emitter ON Voltage		$V_{CE} = -5V, I_{C} = -10mA$		-0.58		V
••			$V_{CE} = -1 \text{ V}, I_{C} = -2 \text{A}$			- 1.5	V
T	Current Gain Bandwidth Product		$V_{CF} = -1V, I_{C} = -250 \text{mA}$	3			MH:

# **Typical Characteristics**

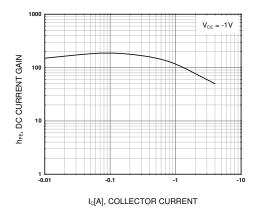


Figure 1. DC current Gain

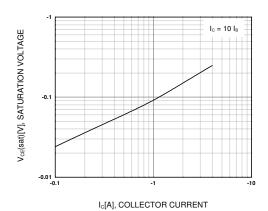


Figure 2. Collector-Emitter Saturation Voltage

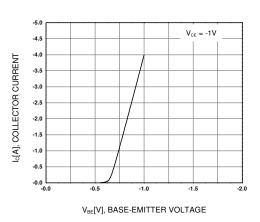


Figure 3. Base-Emitter On Voltage

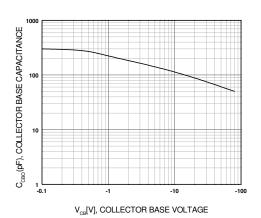


Figure 4. Collector-Base Capacitance

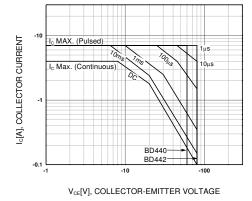


Figure 5. Safe Operating Area

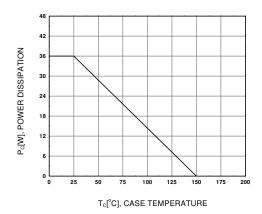


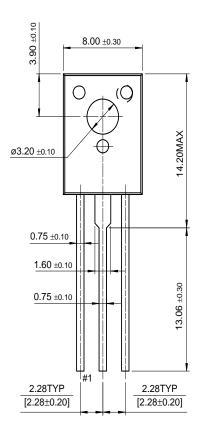
Figure 6. Power Derating

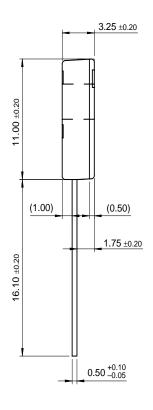
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### **Package Demensions**

TO-126







Dimensions in Millimeters

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Rev. H2

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